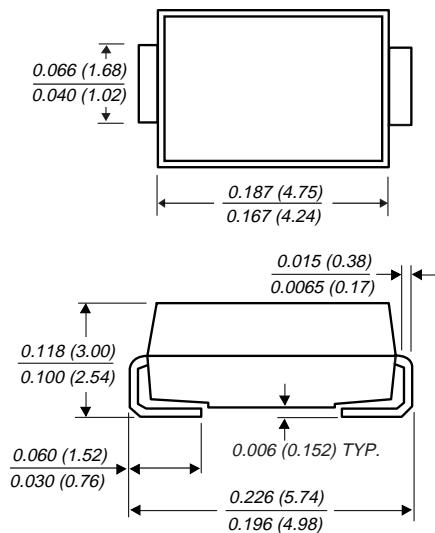



DO-214BA (GF1)

Ultrafast Surface Mount Glass Passivated Rectifier



Mechanical Data

Case: JEDEC DO-214BA, molded plastic over glass body

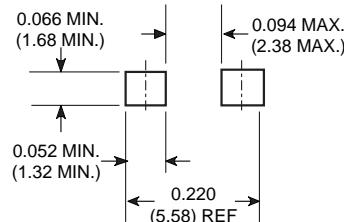
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Weight: 0.0048 oz., 0.120 g

Reverse Voltage 50 to 200V
Forward Current 1.0A

Mounting Pad Layout



Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- Ideal for surface mount automotive applications
- High temperature metallurgically bonded construction
- Superfast recovery times for high efficiency
- Cavity-free glass passivated junction
- Built-in strain relief • Easy pick and place
- High temperature soldering guaranteed: 450°C/5 seconds at terminals.
- Complete device submersible temperature of 265°C for 10 seconds in solder bath

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	EGF1A	EGF1B	EGF1C	EGF1D	Unit
Device Marking Code		EA	EB	EC	ED	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V
Maximum RMS voltage	V _{VRMS}	35	70	105	140	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V
Maximum average forward rectified current at T _L = 125°C	I _{F(AV)}			1.0		A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}			30		A
Typical thermal resistance (Note 1)	R _{θJA} R _{θJL}			85 30		°C/W
Operating junction and storage temperature range	T _{J,TSTG}			-65 to +175		°C

Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	EGF1A	EGF1B	EGF1C	EGF1D	Unit
Maximum instantaneous forward voltage at 1.0A	V _F			1.0		V
Maximum DC reverse current at rated DC blocking voltage	I _R T _A =25°C T _A =125°C			5.0 50		µA
Typical reverse recovery time at I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	t _{rr}			50		ns
Typical junction capacitance at 4V, 1MHz	C _J			15		pF

Note: (1) Thermal resistance from junction to ambient and from junction to lead, P.C.B. mounted on 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas

EGF1A thru EGF1D

Vishay Semiconductors
formerly General Semiconductor



Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Maximum Forward Current Derating Curve

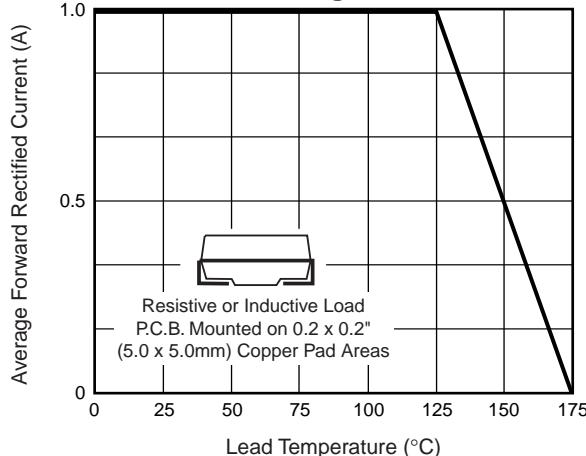


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

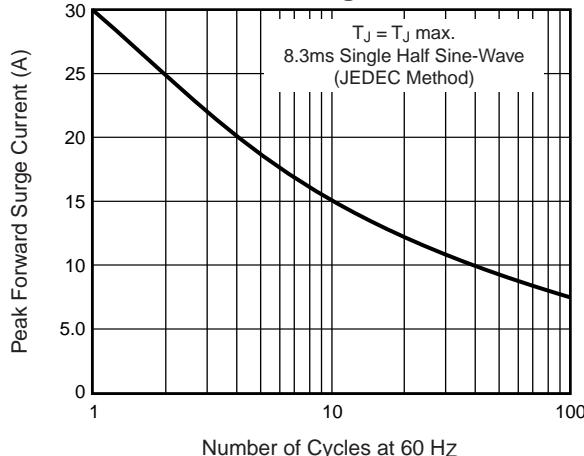


Fig. 3 – Typical Instantaneous Forward Characteristics

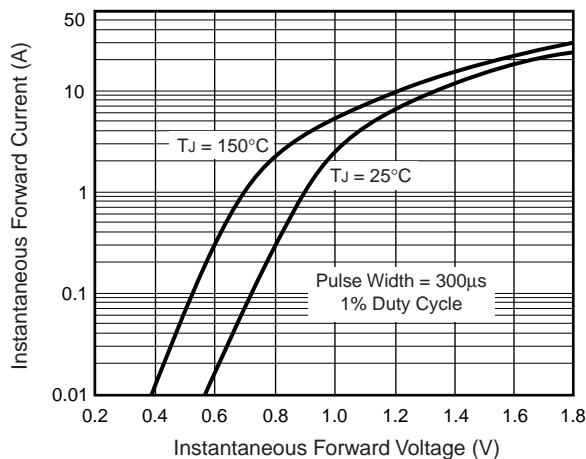


Fig. 4 – Typical Reverse Leakage Characteristics

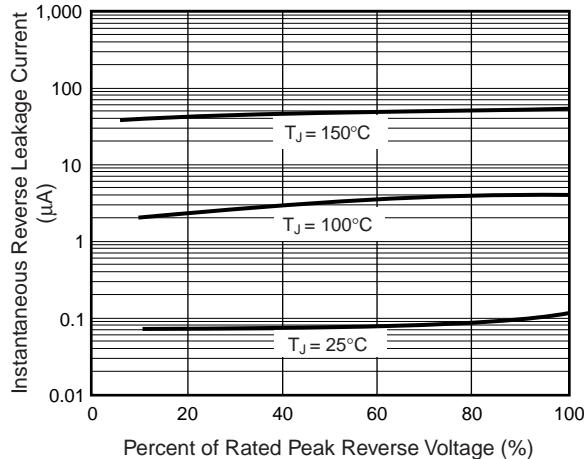


Fig. 5 – Typical Junction Capacitance

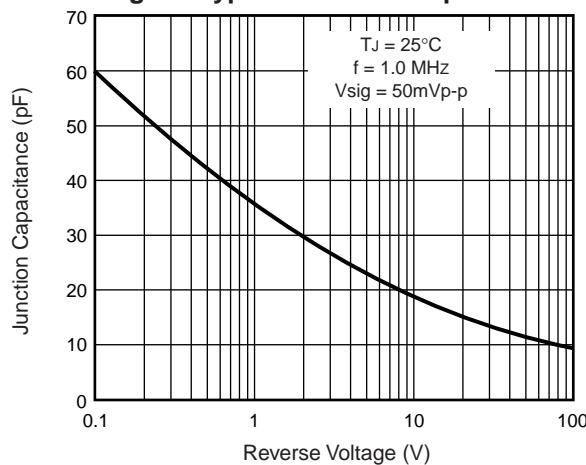


Fig. 6 – Typical Transient Thermal Impedance

